

Power Schottky rectifier

Features

- High current capability
- Avalanche rated
- Low forward voltage drop current
- High frequency operation

Description

Dual diode Schottky rectifier, suited for high frequency switch mode power supply.

Packaged in TO-220AB, this device is intended to be used in notebook, game station and desktop adaptors, providing in these applications a good efficiency at both low and high load.

Table 1. Device summary

$I_{F(AV)}$	2 x 20 A
V_{RRM}	100 V
$T_j (max)$	150 °C
$V_F (typ)$	0.420 V

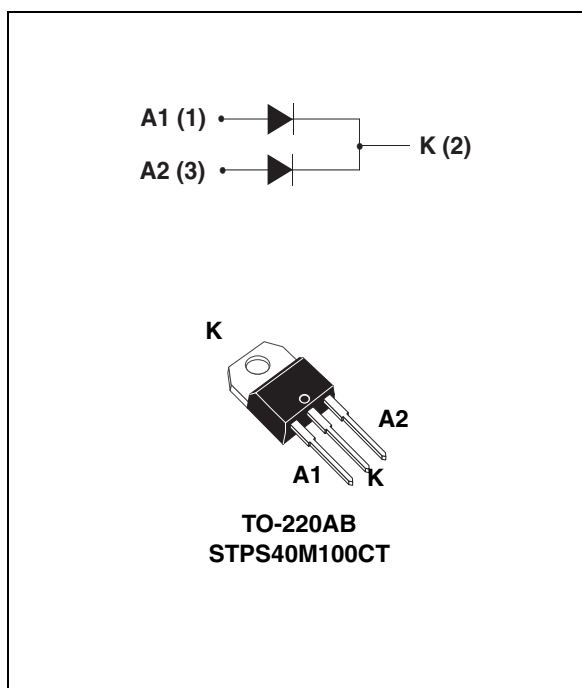
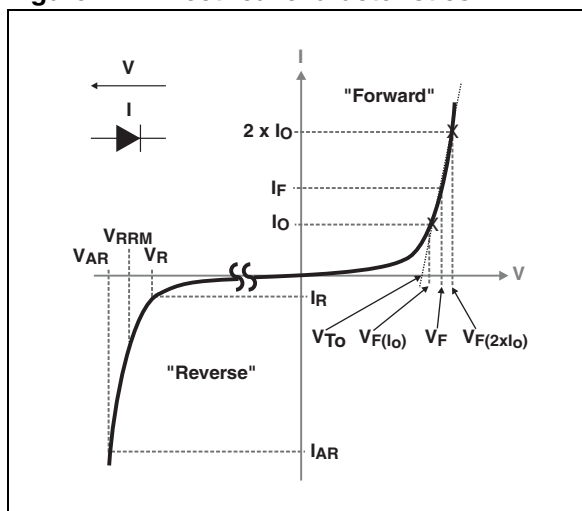


Figure 1. Electrical characteristics (a)



- a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in [Figure 11](#) V_{AR} and I_{AR} are pulse measurements ($t_p < 1 \mu s$). V_R , I_R , V_{RRM} and V_F are static characteristics

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C unless otherwise stated)

Symbol	Parameter		Value	Unit	
V _{RRM}	Repetitive peak reverse voltage		100	V	
I _{F(RMS)}	Forward current rms		60	A	
I _{F(AV)}	Average forward current δ = 0.5	T _c = 125 °C	Per diode	20	A
		T _c = 120 °C	Per package	40	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	530	A	
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power	t _p = 1 μs T _j = 25 °C	23 200	W	
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 1 μs T _j < 150 °C, I _{AR} < 58 A	120	V	
V _{ASM} ⁽²⁾	Maximum single pulse peak avalanche voltage	t _p < 1 μs T _j < 150 °C, I _{AR} < 58 A	120	V	
T _{stg}	Storage temperature range		-65 to + 175	°C	
T _j	Maximum operating junction temperature ⁽³⁾		150	°C	

1. For temperature or pulse time duration deratings, refer to [Figure 4](#), and [Figure 5](#). More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.
2. Refer to [Figure 11](#)
3. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction to case	Per diode	1.4	°C/W
		Total	0.95	
R _{th(c)}	Coupling		0.5	°C/W

When diodes 1 and 2 are used simultaneously

$$T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

Table 4. Static electrical characteristics (terminals 1 and 3 short circuited)

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}			70	μA
		T _j = 125 °C		15	70	mA	
		T _j = 25 °C	V _R = 70 V			40	μA
		T _j = 125 °C		7.5	40	mA	
V _F ⁽²⁾	Forward voltage drop	T _j = 125 °C	I _F = 5 A		0.415	0.500	V
		T _j = 125 °C	I _F = 10A		0.500	0.560	
		T _j = 25 °C	I _F = 20 A			0.780	
		T _j = 125 °C		0.585	0.640		

1. Pulse test: t_p = 5 ms, δ < 2%
2. Pulse test: t_p = 380 μs, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.560 \times I_{F(AV)} + 0.004 \times I_{F(RMS)}^2$$

Figure 2. Average forward power dissipation versus average forward current (per diode)

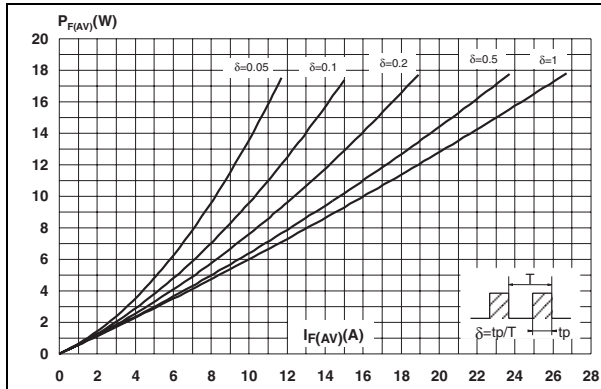


Figure 3. Average forward current versus ambient temperature ($\delta = 0.5$ per diode)

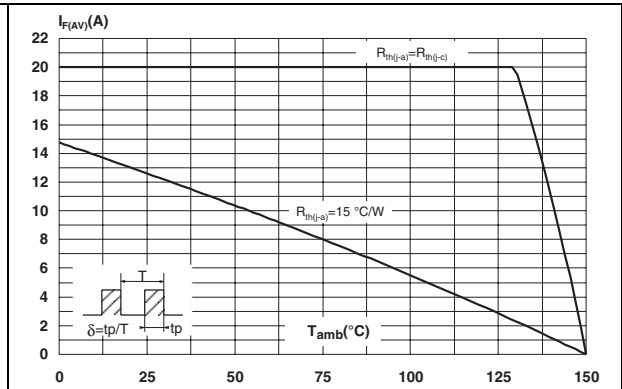


Figure 4. Normalized avalanche power derating versus pulse duration

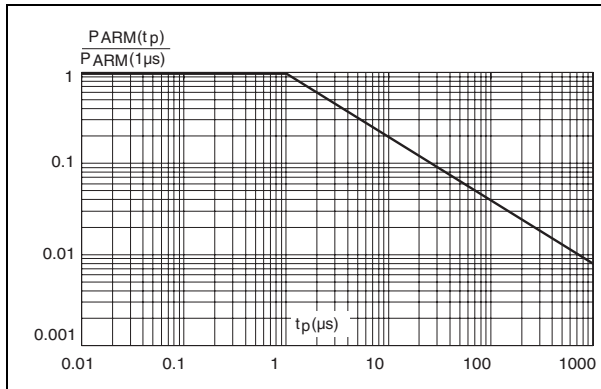


Figure 5. Normalized avalanche power derating versus junction temperature

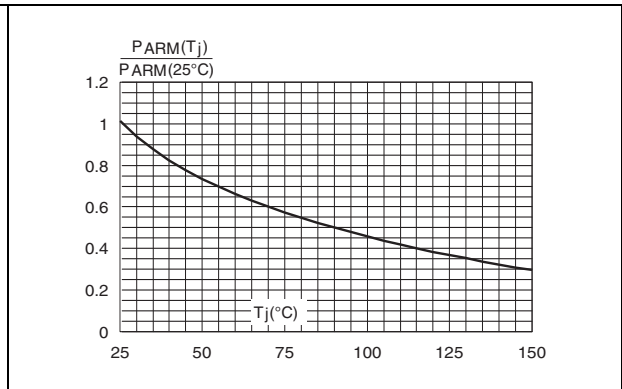


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values per diode)

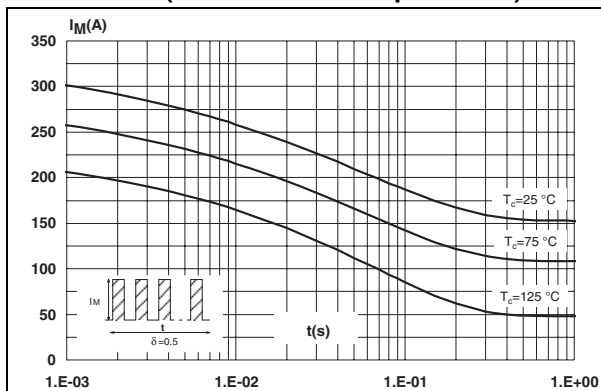


Figure 7. Relative variation of thermal impedance junction to case versus pulse duration

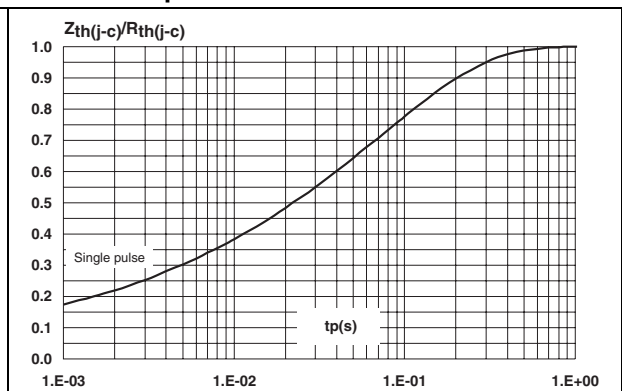


Figure 8. Reverse leakage current versus reverse voltage applied (typical values, per diode)

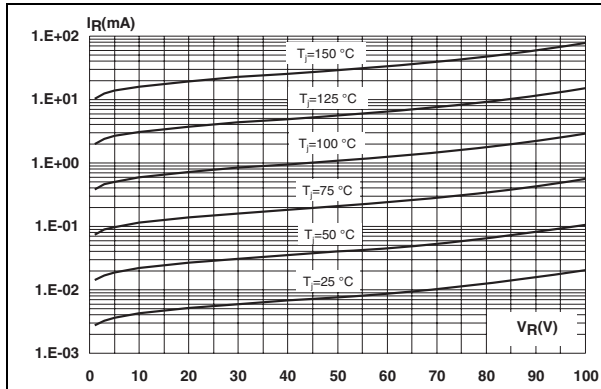


Figure 9. Junction capacitance versus reverse voltage applied (typical values, per diode)

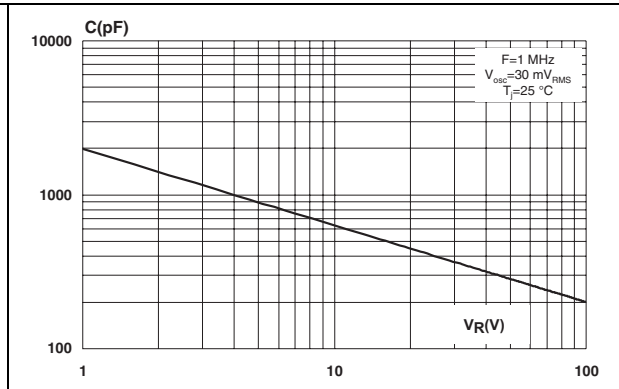


Figure 10. Forward voltage drop versus forward current (per diode)

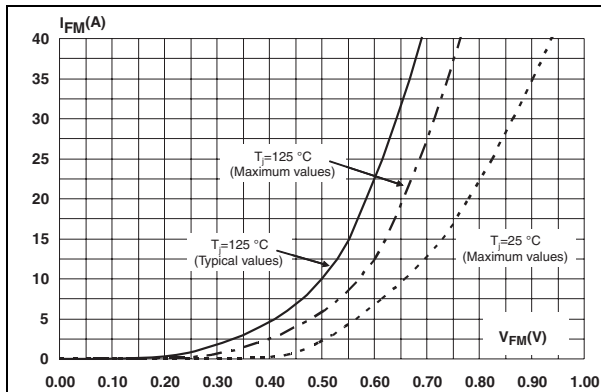
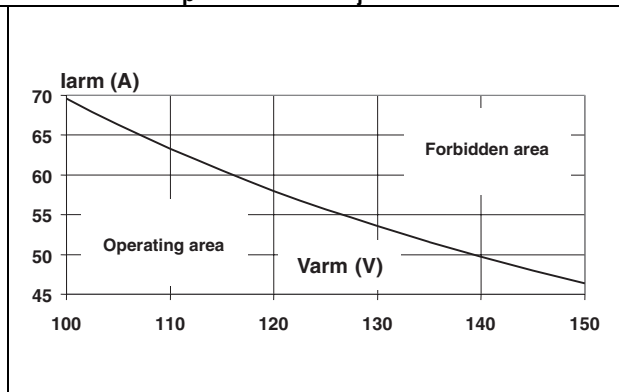


Figure 11. Reverse safe operating area ($t_p < 1 \mu s$ and $T_j < 150$ °C)



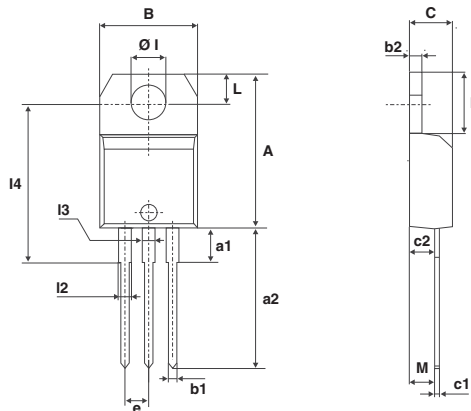
2 Package information

- Epoxy meets UL94, V0
- Cooling method: C
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 5. TO-220AB dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
l4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
l2	1.14		1.70	0.044		0.066
l3	1.14		1.70	0.044		0.066
M		2.60			0.102	



3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS40M100CT	STPS40M100CT	TO-220AB	2.2 g	50	Tube

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
25-Mar-2009	1	First issue

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